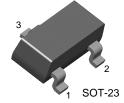


BC846/847/848/849/850

Switching and Amplifier Applications • Suitable for automatic insertion in thick and thin-film circuits

- Low Noise: BC849, BC850
- Complement to BC856 ... BC860



1. Base 2. Emitter 3. Collector

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage		
020	: BC846	80	V
	: BC847/850	50	V
	: BC848/849	30	V
V_{CEO}	Collector-Emitter Voltage		
	: BC846	65	V
	: BC847/850	45	V
	: BC848/849	30	V
V_{EBO}	Emitter-Base Voltage		
	: BC846/847	6	V
	: BC848/849/850	5	V
I _C	Collector Current (DC)	100	mA
I _C P _C	Collector Power Dissipation	310	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-65 ~ 150	°C

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I _{CBO}	Collector Cut-off Current	$V_{CB}=30V$, $I_{E}=0$			15	nA
h _{FE}	DC Current Gain	V _{CE} =5V, I _C =2mA	110		800	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =10mA, I _B =0.5mA I _C =100mA, I _B =5mA		90 200	250 600	mV mV
V _{BE} (sat)	Collector-Base Saturation Voltage	I _C =10mA, I _B =0.5mA I _C =100mA, I _B =5mA		700 900		mV mV
V _{BE} (on)	Base-Emitter On Voltage	V_{CE} =5V, I_{C} =2mA V_{CE} =5V, I_{C} =10mA	580	660	700 720	mV mV
f _T	Current Gain Bandwidth Product	V _{CE} =5V, I _C =10mA, f=100MHz		300		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz		3.5	6	pF
C _{ib}	Input Capacitance	V _{EB} =0.5V, I _C =0, f=1MHz		9		pF
NF	Noise Figure : BC846/847/848 : BC849/850 : BC849 : BC850	V_{CE} =5V, I_{C} =200 μ A f=1KHz, R_{G} =2K Ω V_{CE} =5V, I_{C} =200 μ A R_{G} =2K Ω , f=30~15000Hz		2 1.2 1.4 1.4	10 4 4 3	dB dB dB dB

h_{FE} Classification

Classification	А	В	С
h _{FE}	110 ~ 220	200 ~ 450	420 ~ 800

Marking Code

Type	846 847			848			849			850					
Type	Α	В	С	Α	В	С	Α	В	С	Α	В	С	Α	В	С
Mark	8AA	8AB	8AC	8BA	8BB	8BC	8CA	8CB	8CC	8DA	8DB	8DC	8EA	8EB	8EC

Typical Characteristics

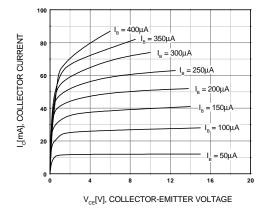


Figure 1. Static Characteristic

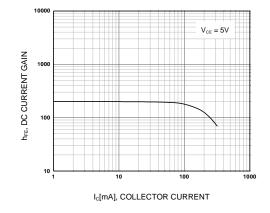


Figure 2. DC current Gain

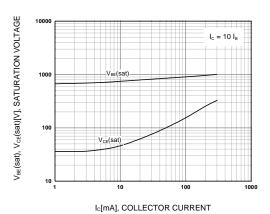


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

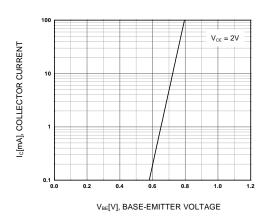


Figure 4. Base-Emitter On Voltage

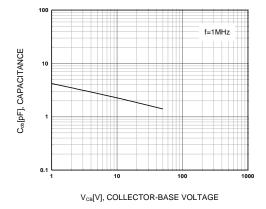


Figure 5. Collector Output Capacitance

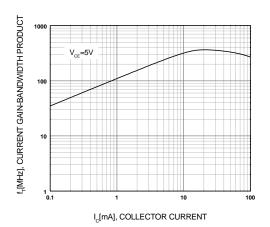
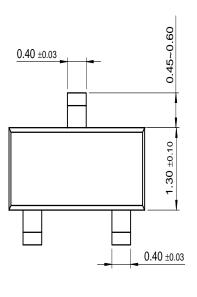


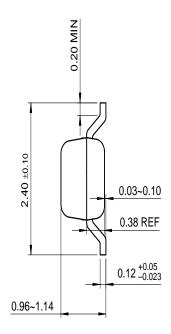
Figure 6. Current Gain Bandwidth Product

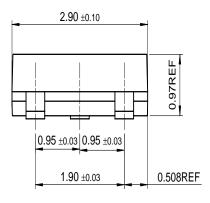
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Package Dimensions

SOT-23







Dimensions in Millimeters

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Bottomless™	FAST [®]	LittleFET™	Power247™	SuperSOT™-3
CoolFET™	FASTr™	MicroFET™	PowerTrench [®]	SuperSOT™-6
$CROSSVOLT^{TM}$	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I^2C^{TM}	OCX^{TM}	RapidConfigure™	UHC™
Across the board.	Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
The Power Franci	hise™	OPTOLOGIC [®]	SILENT SWITCHER®	VCX TM
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.			
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